NSN 5962-01-535-6003

Memory Microcircuit - Page 1 of 1



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Features Provided:

Electrostatic sensitive and ultraviolet erasable and monolithic and programmable

Inclosure Material:

Ceramic

Inclosure Configuration:

Dual-in-line

Output Logic Form:

Complementary-metal oxide-semiconductor logic

Memory Device Type:

Pal

Terminal Type And Quantity:

24 printed circuit

Shelf Life:

N/a

Unit Of Measure:

--Demilitarization:

Yes - demil/mli

Fiig:

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